

V _{CES}	650V
I _{C(100°C)}	17A
V _{CE(sat) (Typ.)}	1.6V@I _C =30A
P _D	61W

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating ; RoHS Compliant

Applications

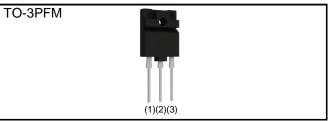
PFC

UPS

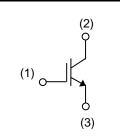
Power Conditioner

IH

Outline



Inner Circuit





Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Tuno	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGTH60TK65

•Absolute Maximum Ratings (at $T_C = 25^{\circ}C$ unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V _{GES}	±30	V
Collector Current	$T_{\rm C} = 25^{\circ}{\rm C}$	Ι _C	28	А
Collector Current	$T_{\rm C} = 100^{\circ}{\rm C}$	Ι _C	17	А
Pulsed Collector Current		ا _{CP} *1	120	А
Power Dissinction	$T_{\rm C} = 25^{\circ}{\rm C}$	P _D	61	W
Power Dissipation	$T_{\rm C} = 100^{\circ}{\rm C}$	P _D	30	W
Operating Junction Temperature		Tj	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

*1 Pulse width limited by T_{jmax.}

•Thermal Resistance

Parameter	Symbol	Values		Unit	
Parameter		Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	2.43	°C/W

•IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
Faranieler	Symbol Conditions -		Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV _{CES}	I _C = 10μΑ, V _{GE} = 0V	650	-	-	V
Collector Cut - off Current	I _{CES}	V _{CE} = 650V, V _{GE} = 0V	-	-	10	μA
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V, V_{CE} = 0V$	-	-	±200	nA
Gate - Emitter Threshold Voltage	V _{GE(th)}	$V_{CE} = 5V, I_{C} = 21.0mA$	4.5	5.5	6.5	V
Collector - Emitter Saturation Voltage	V _{CE(sat)}	$I_{C} = 30A, V_{GE} = 15V$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.6 2.1	2.1 -	V

•IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Doromotor	Cumb al	Quantitiana	Values			L La M	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Input Capacitance	C _{ies}	V _{CE} = 30V	-	1670	-		
Output Capacitance	C _{oes}	$V_{GE} = 0V$	-	66	-	pF	
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	27	-		
Total Gate Charge	Q_g	V _{CE} = 300V	-	58	-		
Gate - Emitter Charge	Q_{ge}	I _C = 30A	-	15	-	nC	
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	20	-		
Turn - on Delay Time	t _{d(on)}	$I_{\rm C} = 30$ A, $V_{\rm CC} = 400$ V	-	27	-		
Rise Time	t _r	$V_{GE} = 15V, R_{G} = 10\Omega$	-	40	-		
Turn - off Delay Time	t _{d(off)}	T _j = 25°C	-	105	-	ns	
Fall Time	t _f	Inductive Load	-	47	-		
Turn - on Delay Time	t _{d(on)}	$I_{\rm C} = 30$ A, $V_{\rm CC} = 400$ V	-	27	-		
Rise Time	t _r	$V_{GE} = 15V, R_{G} = 10\Omega$	-	40	-		
Turn - off Delay Time	t _{d(off)}	T _j = 175°C	-	120	-	ns	
Fall Time	t _f	Inductive Load	-	59	-		
		$I_{\rm C} = 120$ A, $V_{\rm CC} = 520$ V					
Reverse Bias Safe Operating Area	RBSOA	V _P = 650V, V _{GE} = 15V	FU	LL SQUA	RE	-	
		$R_{G} = 60\Omega, T_{j} = 175^{\circ}C$					

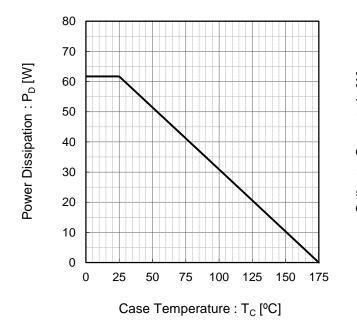


Fig.1 Power Dissipation vs. Case Temperature

Fig.2 Collector Current vs. Case Temperature

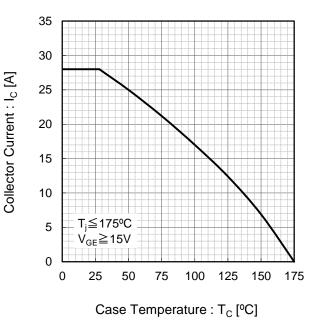
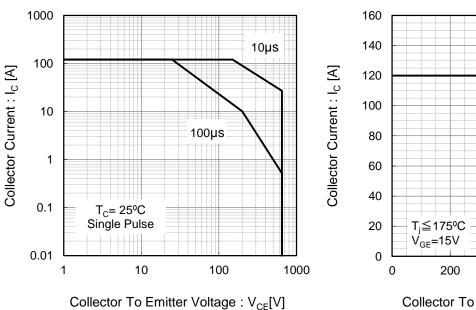
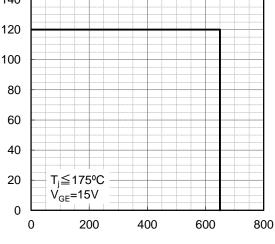


Fig.3 Forward Bias Safe Operating Area

Fig.4 Reverse Bias Safe Operating Area





Collector To Emitter Voltage : $V_{CE}[V]$

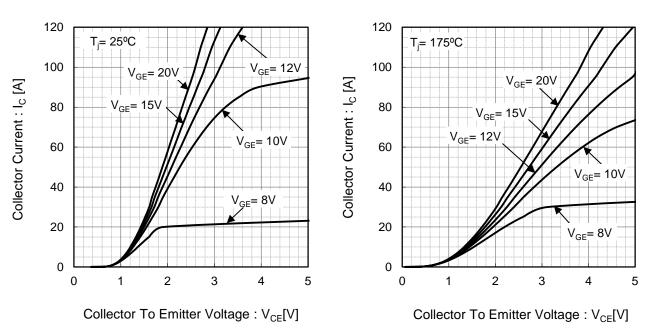
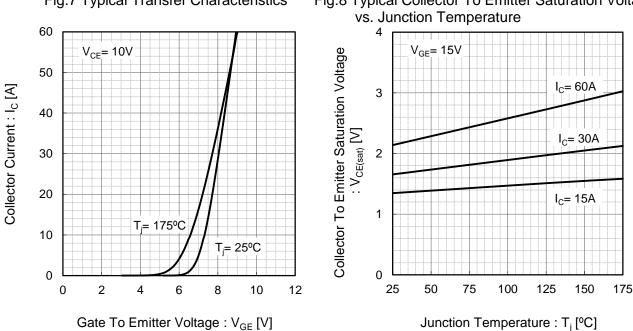


Fig.5 Typical Output Characteristics

Fig.8 Typical Collector To Emitter Saturation Voltage



Junction Temperature : T_i [°C]

Fig.7 Typical Transfer Characteristics

Fig.6 Typical Output Characteristics

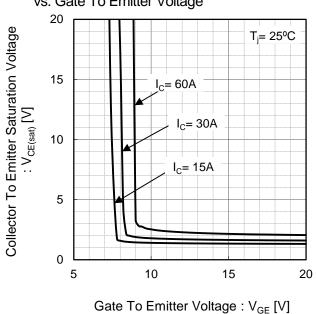


Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage

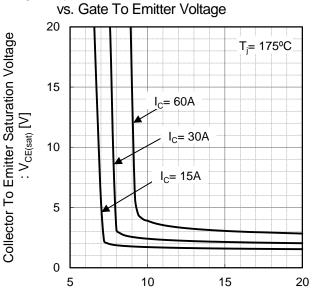
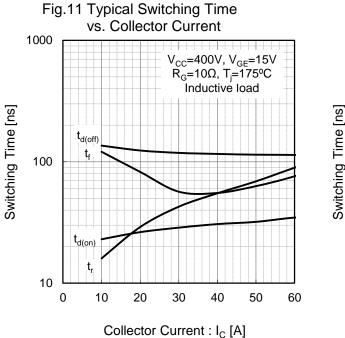
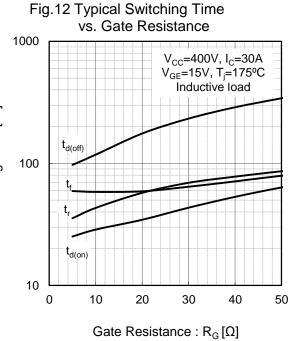
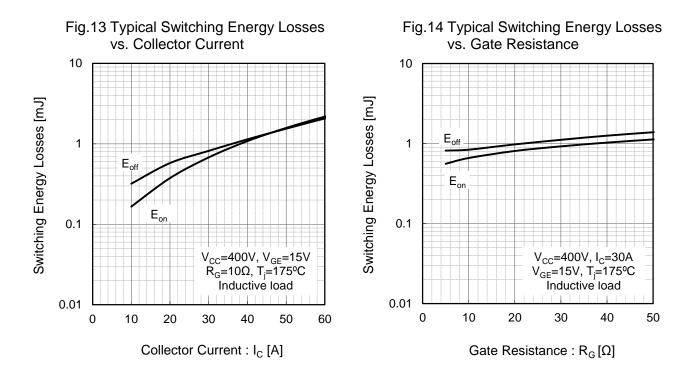


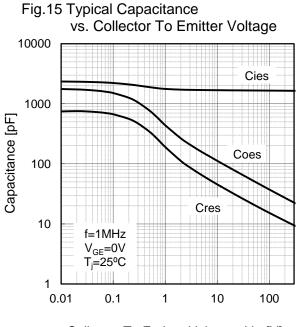
Fig.10 Typical Collector To Emitter Saturation Voltage

Gate To Emitter Voltage : V_{GE} [V]



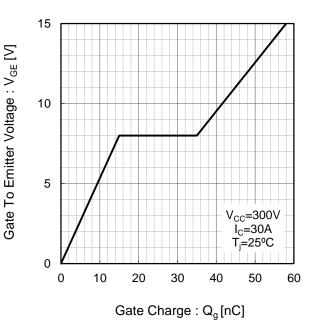






Collector To Emitter Voltage : V_{CE}[V]

Fig.16 Typical Gate Charge



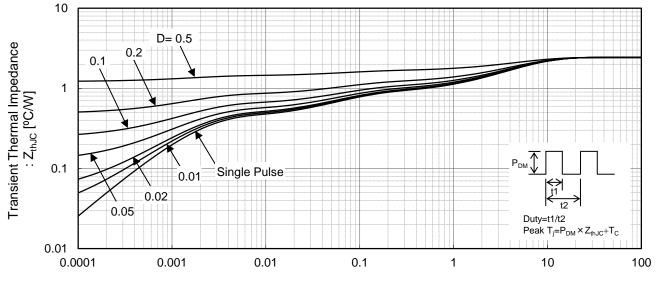


Fig.17 IGBT Transient Thermal Impedance

Pulse Width : t1[s]

●Inductive Load Switching Circuit and Waveform

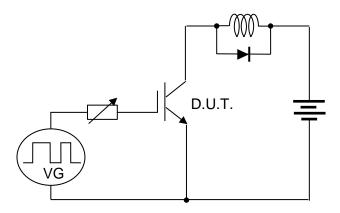
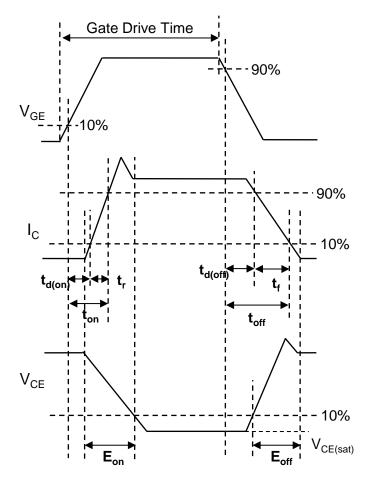


Fig.18 Inductive Load Circuit





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